TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# TC74HC193AP, TC74HC193AF, TC74HC193AFN

#### SYNCHRONOUS UP/DOWN BINARY COUNTER

The TC74HC193A are high speed CMOS SYNCHRONOUS 4-BIT UP/DOWN COUNTER fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

They have a clear input (CLR), a load input ( $\overline{LOAD}$ ), load data inputs (A ~ D), two clock inputs (COUNT UP, COUNT DOWN), four count data outputs (QA ~ QD), and other outputs ( $\overline{CARRY}$ ,  $\overline{BORROW}$ ).

CLEAR is active high and forces QA thru QD outputs low independent of the other inputs.

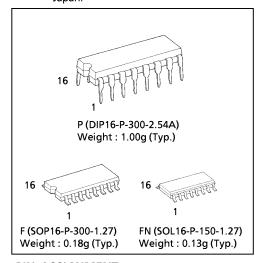
CARRY and BORROW outputs are provided in order to make a cascade connection without external circuitry.

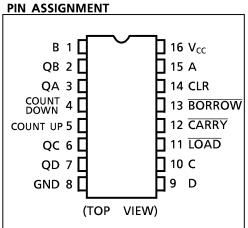
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### FEATURES:

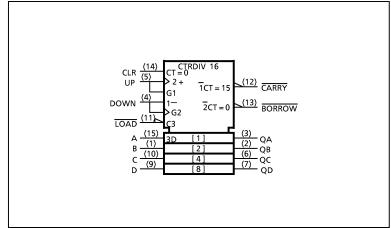
- High Speed------f<sub>MAX</sub> = 54MHz (typ.)
  - at  $V_{CC} = 5V$
- Low Power Dissipation ············· $I_{CC} = 4\mu A(Max.)$  at Ta = 25°C
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (Min.)
- Output drive Capability ..... 10 LSTTL Loads
- Symmetrical Output Impedance… | I<sub>OH</sub> | = I<sub>OL</sub> = 4mA (Min.)
- Balanced Propagation Delays ····· t<sub>pLH</sub> ≃ t<sub>pHL</sub>
- Wide Operating Voltage Range.... V<sub>CC</sub> (opr.) = 2V~6V
- Pin and Function Compatible with 74LS193

# (Note) The JEDEC SOP (FN) is not available in Japan.



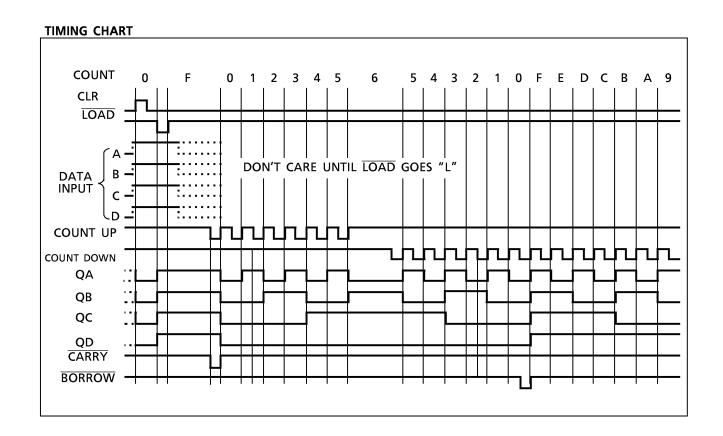


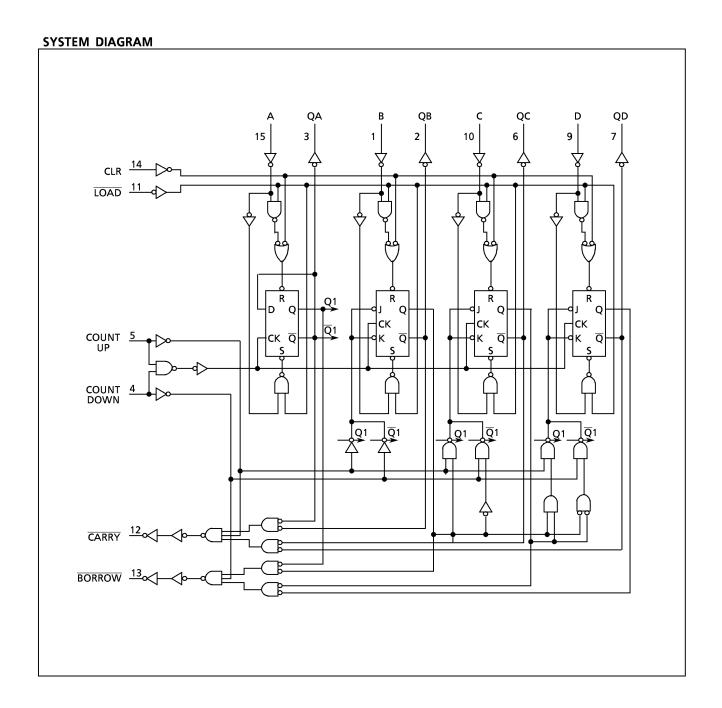
#### **IEC LOGIC SYMBOL**



#### TRUTH TABLE

	INP					
COUNT UP	COUNT DOWN	LOAD	CLR	FUNCTION		
<u>_</u>	Н	Н	L	COUNT UP		
\bar{\bar{\bar{\bar{\bar{\bar{\bar{	Н	Н	L	NO COUNT		
Н		Н	L	COUNT DOWN		
Н	T_	Н	L	NO COUNT		
Х	Х	L	L	PRESET		
Х	Х	Х	Н	RESET		





#### **ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V <sub>cc</sub>	<b>−</b> 0.5~7	٧
DC Input Voltage	VIN	$-0.5 \sim V_{CC} + 0.5$	V
DC Output Voltage	V <sub>OUT</sub>	$-0.5 \sim V_{CC} + 0.5$	V
Input Diode Current	I <sub>IK</sub>	± 20	mA
Output Diode Current	I <sub>OK</sub>	±20	mA
DC Output Current	I <sub>OUT</sub>	± 25	mA
DC V <sub>CC</sub> / Ground Current	I <sub>cc</sub>	± 50	mA
Power Dissipation	P <sub>D</sub>	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T <sub>stg</sub>	<b>−65~150</b>	°C

\*500mW in the range of Ta =  $-40^{\circ}$ C~65°C. From Ta = 65°C to 85°C a derating factor of -10mW/°C shall be applied until 300mW.

#### **RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V <sub>cc</sub>	2~6	V
Input Voltage	V <sub>IN</sub>	0~V <sub>CC</sub>	V
Output Voltage	V <sub>OUT</sub>	0~V <sub>CC</sub>	V
Operating Temperature	T <sub>opr</sub>	<b>−40~85</b>	°C
Input Rise and Fall Time	t <sub>r</sub> , t <sub>f</sub>	$0 \sim 1000 (V_{CC} = 2.0V)$ $0 \sim 500 (V_{CC} = 4.5V)$ $0 \sim 400 (V_{CC} = 6.0V)$	ns

#### DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CO	MOITION	V <sub>cc</sub>	T	a = 25°0	С	Ta = -4	l0~85°C	UNIT
FARAIVIETER	STIVIBUL	1231 CO	TEST CONDITION		MIN.	TYP.	MAX.	MIN.	MAX.	ONIT
High - Level Input Voltage	VIH				1.50 3.15 4.20		_ _ _	1.50 3.15 4.20		٧
Low - Level Input Voltage	VIL			2.0 4.5 6.0	111		0.50 1.35 1.80	_ _ _	0.50 1.35 1.80	٧
High - Level	V <sub>он</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -20\mu A$	2.0 4.5 6.0	1.9 4.4 5.9	2.0 4.5 6.0		1.9 4.4 5.9		v
Output Voltage			$I_{OH} = -4 \text{ mA}$ $I_{OH} = -5.2 \text{ mA}$	4.5 6.0	4.18 5.68	4.31 5.80	_	4.13 5.63	_	
Low - Level Output Voltage	V <sub>OL</sub>	V <sub>IN</sub> =	I <sub>OL</sub> = 20μΑ	2.0 4.5 6.0		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1	v
		V <sub>IH</sub> or V <sub>IL</sub>	$I_{OL} = 4  mA$ $I_{OL} = 5.2  mA$	4.5 6.0	1 1	0.17 0.18	0.26 0.26	_	0.33 0.33	
Input Leakage Current	I <sub>IN</sub>	$V_{IN} = V_{CC}$ or GND		6.0	ı	1	± 0.1	_	± 1.0	
Quiescent Supply Current	I <sub>cc</sub>	$V_{1N} = V_{C}$	<sub>c</sub> or GND	6.0	_	_	4.0	_	40.0	μΑ

# TIMING REQUIREMENTS (Input $t_r = t_f = 6ns$ )

PARAMETER	SYMBOL	TEST CONDITION		Ta =	25°C	Ta = −40~85°C	UNIT
TARAMETER	3 TIVIBOL	1231 CONDITION	V <sub>CC</sub> (V)	TYP.	LIMIT	LIMIT	CIVII
Minimum Pulse Width	t <sub>W(H)</sub>		2.0	_	100	125	
(CK)	t <sub>W(L)</sub>		4.5	_	20	25	
(CK)	CVV(L)		6.0		17	21	<u> </u>
Minimum Pulse Width			2.0	_	75	95	
(LOAD)	t <sub>W(L)</sub>		4.5	_	15	19	
(LOAD)			6.0		13	16	<b>↓  </b>
Minimum Hold Time			2.0	_	100	125	
(CLR)	t <sub>W(H)</sub>		4.5	_	20	25	
(32.17)			6.0		17	21	. I
Minimum Set-up Time			2.0	_	75	95	
(DATA-LOAD)	t <sub>s</sub>		4.5	_	15	19	ns
(DATA LOAD)			6.0	_	13	16	<u> </u>
Minimum Hold Time	t <sub>h</sub>		2.0	_	O O	0	
(DATA-LOAD)			4.5	_	0	0	
(BATA LOAD)			6.0		0	0	<u> </u>
Minimum Removal Time			2.0	_	50	65	
	t <sub>rem</sub>		4.5	_	10	13	
(LOAD)			6.0		9	10	
Minimum Pomoval Timo			2.0	_	50	65	
Minimum Removal Time ( CLR )	t <sub>rem</sub>		4.5	_	10	13	
			6.0		9	10	
			2.0	<del></del>	5	4	
Clock Frequency	f		4.5	_	25	20	MHz
			6.0	_	29	24	

# AC ELECTRICAL CHARACTERISTICS ( $C_L = 15 pF$ , $V_{CC} = 5 V$ , $Ta = 25 ^{\circ}C$ , Input $t_r = t_f = 6 ns$ )

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Transition Time	t <sub>TLH</sub> t <sub>THL</sub>		_	6	12	
Propagation Delay Time (UP, DOWN—Q)	t <sub>pLH</sub> t <sub>pHL</sub>		_	16	33	
Propagation Delay Time (UP—CARRY)	t <sub>pLH</sub> t <sub>pHL</sub>		_	10	22	
Propagation Delay Time (DOWN—BORROW)	t <sub>pLH</sub> t <sub>pHL</sub>		_	10	22	
Propagation Delay Time ( LOAD — Q )	t <sub>pLH</sub> t <sub>pHL</sub>		_	21	38	
Propagation Delay Time ( LOAD — CARRY )	t <sub>pLH</sub> t <sub>pHL</sub>		_	25	44	
Propagation Delay Time ( LOAD — BORROW )	t <sub>pLH</sub> t <sub>pHL</sub>		_	26	44	ns
Propagation Delay Time (DATA IN-Q)	t <sub>pLH</sub> t <sub>pHL</sub>		_	21	33	
Propagation Delay Time (DATA IN—CARRY)	t <sub>pLH</sub> t <sub>pHL</sub>		_	29	44	
Propagation Delay Time (DATA IN—BORROW)	t <sub>pLH</sub> t <sub>pHL</sub>		_	26	44	
Propagation Delay Time (CLR—Q)	t <sub>pHL</sub>		_	25	39	
Propagation Delay Time (CLR—CARRY)	t <sub>pLH</sub>		_	30	44	
Propagation Delay Time (CLR—BORROW)	t <sub>pHL</sub>		_	30	44	
Maximum Clock Frequency	f <sub>MAX</sub>		27	52	_	MHz

# AC ELECTRICAL CHARACTERISTICS ( $C_L = 50pF$ , Input $t_r = t_f = 6ns$ )

PARAMETER	SYMBOL	TEST CONDITION			Ta = 25°0		Ta = -4	UNIT								
TANAMETER	JINDOL	1231 CONDITION	V <sub>cc</sub> (V)	MIN.	TYP.	MAX.	MIN.	MAX.	JUNIT							
Output Transition Time	t <sub>TLH</sub>		2.0 4.5	_	30 8	75 15		95 19								
Output Transition Time	t <sub>THL</sub>		6.0	_	7	13	_	16								
Propagation Delay Time	t <sub>pLH</sub>		2.0	_	65	190	_	240								
(UP, DOWN-Q)	t <sub>pHL</sub>		4.5 6.0	_	20 16	38 32	_	48 41								
. ,	<del>  '</del>		2.0	_	40	130	_	165	1							
Propagation Delay Time (UP—CARRY)	t <sub>pLH</sub>		4.5	_	13	26	_	33								
(UP-CARRY)	t <sub>pHL</sub>		6.0	_	11	22		28	4							
Propagation Delay Time	t <sub>pLH</sub>		2.0 4.5	_	40 13	130 26	_	165 33								
(DOWN-BORROW)	t <sub>pHL</sub>		6.0	_	11	22	_	28								
Propagation Delay Time	t <sub>pLH</sub>		2.0	_	85	220	_	275								
(LOAD-Q)	t <sub>pHL</sub>		4.5 6.0	_	25 20	44 37	_	55 47								
Daniel Dale Time	+		2.0	_	110	250	<del> </del>	315	1							
Propagation Delay Time (LOAD—CARRY)	t <sub>pLH</sub>		4.5	_	30	50	_	63								
, , , , , , , , , , , , , , , , , , ,	t <sub>pHL</sub>		6.0 2.0		25 110	43 250	_	54 315	-							
Propagation Delay Time	t <sub>pLH</sub>		4.5	_	30	250 50	_	63	ns							
( <del>IOAD</del> —BORROW)	t <sub>pHL</sub>		6.0	_	25	43	_	54	]							
Propagation Delay Time	t <sub>pLH</sub>		2.0	_	80	190	_	240								
(DATA IN-Q)	t <sub>pHL</sub>		4.5 6.0	_	25 20	38 32		48 41								
Propagation Delay Time	+		2.0	_	120	250	_	315	1							
(DATA IN—CARRY)	t <sub>pLH</sub> t <sub>pHL</sub>		4.5	_	34	50	-	63								
•	<del>                                     </del>		6.0 2.0		28 110	43 250		54 315	-							
Propagation Delay Time	t <sub>pLH</sub>		4.5	_	31	50	_	63								
(DATA IN-BORROW)	t <sub>pHL</sub>		6.0	_	25	43	_	54								
Propagation Delay Time	1		2.0 4.5	_	100 30	225 45		280 56								
(CLR-Q)	t <sub>pHL</sub>		6.0	_	25	38	_	48								
Propagation Delay Time			2.0	_	120	250	<b>—</b>	315	1							
(CLR—CARRY)	t <sub>pLH</sub>		4.5	_	35 29	50	_	63								
, ,			6.0 2.0		120	43 250	<del>  _</del>	54 315	-							
Propagation Delay Time	t <sub>pHL</sub>		4.5	_	35	50	_	63								
(CLR—BORROW)	F		6.0		29	43		54								
Maximum Clock Frequency	f <sub>MAX</sub>		2.0 4.5	5 25	12 48	_	20	_	MHz							
waxiiiiuiii Clock Frequency	'MAX		6.0	29	55	_	24	_	1411 12							
Input Capacitance	C <sub>IN</sub>		•	_	5	10	_	10								
Power Dissipation Capacitance				_	67	_	<u> </u>	_	pF							
		the internal equi	wolont	comocit		Power Dissipation Capacitance $ C_{PD}(1) $ $ C_{PD} $ is defined as the value of the internal equivalent capacitance which is calculated from the										

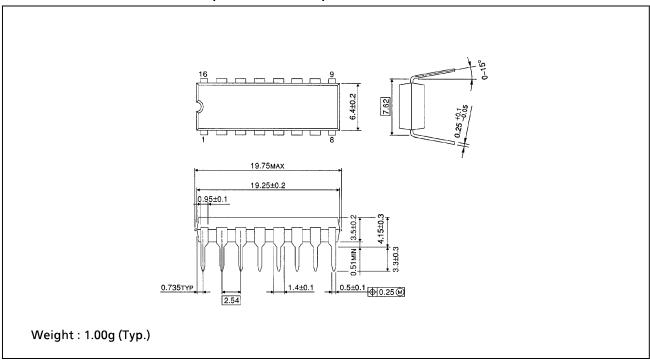
Note (1) C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC}$  (opr) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

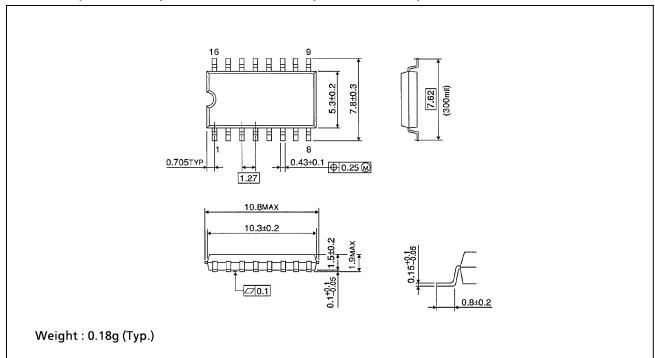
### DIP 16PIN PACKAGE DIMENSIONS (DIP16-P-300-2.54A)

Unit in mm



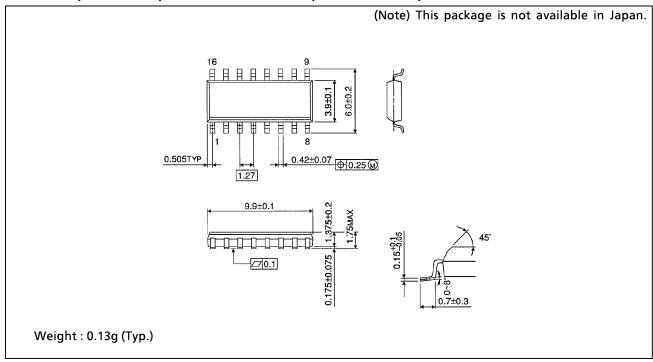
# SOP 16PIN (200mil BODY) PACKAGE DIMENSIONS (SOP16-P-300-1.27)

Unit in mm



# SOP 16PIN (150mil BODY) PACKAGE DIMENSIONS (SOL16-P-150 -1.27)

Unit in mm



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